												RE	VIS	ON	5						
						.TR				DES	CRII	PTIC	N				DAT	E	AP	PRO	VED
	•			Sole source Rays				ayth	tary drawing format. ytheon requires nges in order to				987		RPEva		~				
										,			-								
URREN	TC	AG	iΕ	CC)E	Œ	67	72	68												
REV	TĪ	T	T	$\overline{\Box}$					Ť	T	1	Г	П	T	T	T			П	T	Т
PAGE		I																		1	I
REV STATUS OF PAGES	REV	A		A 3	A 4		A	A		<u> </u>	╀		$\vdash \vdash$	+	-	 _		_	Н	4	4
	PAGE	8 1	2	13		5	6	7	8	9	╁		Щ			<u> </u>	닏		Ц		ㅗ
	ics		77)OI	Ŝ			K	QQQ	who			LIT							IN	G
				ECK	_	_				_	al	l De	partm	ents	and	Age	ncies	of	the		
Supply Center					V	٧Ŀ	<u>ර</u>	1	36	<u> </u>			. MIC	_			1 700	- 4.0	DUA	C.E.	
Supply Center			B	<u>u</u>								T1 5	. ITA	UOCTI	COT		LIME	AR,	PRA	12E-	
Pupply Center Payton, Ohio Priginal date f drawing: 14	Decemb	er	PEX		NEI VEI	*[3 6	ر. در	an	ه	<u> </u>		LUC	KED L OLITH	UUP.	212	II EM,				
	Decemb 987	er	P SIZ		C.) 3:	T.		L	WG	MON	OLITI	IC S	SILI	II EM,	•			

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

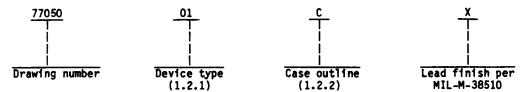
DESC FORM 193

MAY 86



1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type. The device type shall identify the circuit function as follows:

Device type Generic number Circuit function

O1 XR-2211M Phase-locked loop system

1.2.2 <u>Case outline</u>. The case outline shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter

Case outline

C

D-1 (14-pin, $1/4^{\circ}$ x $3/4^{\circ}$), dual-in-line package

1.3 Absolute maximum ratings.

1.4 Recommended operating conditions.

1/ For T_A > +25°C, derate linearly 6 mW/°C.

MILITARY DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO

SIZE
A
77050

REV
A
PAGE 2



2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - 3. REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Case outline. The case outline shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

MILITARY DRAWING	SIZE A		DWG NO. 77050				
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO		·	REV	A		PAGE	3

		ctrical performance characte		· · · · · · · · · · · · · · · · · · ·		+
Test	Symbol	Conditions -55°C < T _A < +125°C unless otherwise specified	Group A subgroups		mits Max	Unit
OSCILLATOR	· · · · · · · · · · · · · · · · · · · ·	1 anness concluses spectified				•
Supply current	Icc		1 1	 	9	mA
			2, 3		12	T I
Frequency accuracy	fosc	Deviation from $F_0 = 1/R_0C_0$	4		± 3	%
			5, 6		±8	
Frequency stability 1/ temperature coefficient	Δf t(min)-t(max)	$R_0 = 500 \text{ k}\Omega$, $C_0 = 2.0 \text{ nF}$	4, 5, 6		±50	ppm/°
Power supply rejection	 PSRR		4	.01	0.5	%/V
ratio	1		5, 6		2.0	T
Upper frequency limit	∆fOSC(max)	$R_0 = 8.2 \text{ k}\Omega$, $C_0 = 400 \text{ pF}$	7	100	1x10 ³	kHz
Lowest operating frequency	fosc(min)	$R_0 = 2 M\Omega$, $C_0 = 50 \mu F$	7		.01	Hz
TIMING RESISTOR, RO	See figure 4					
Operating range	R ₀₁	See figures 2 and 3	7	5	2,000	kΩ
Recommended range 1/	R ₀₂	T 	7	15	100	kΩ
LOOP PHASE DETECTOR						
Peak output current	IOP	 Measured at pin 11	ŀ	 ±150	±300	<u> </u> μ Α
			2, 3	±100	±350	
Maximum swing	v _o	Referenced to pin 10	1	±4		Į v
			2, 3	±3.5	<u> </u>	<u> </u>
QUADRATURE PHASE DETECTOR				r -		
Peak output current	IOP	Measured at pin 3	1	100 	750	 μ Α
Maximum swing	v ₀		1	5	12	V _{pp}
See footnotes at end of tab	ole.					
MILITARY DRA		SIZE	DWG NO	77050	. 10-11,	
DEFENSE ELECTRONICS SUI DAYTON, OHIO		REV		PAGE		

Test	Symbol	Conditions	Group A	Lfi	nits	ͺ Unit
		-55°C < TA < +125°C unless otherwise specified	subgroups	Min	Max_	<u> </u>
INPUT PREAMP	•					
Input signal (voltage required to cause limiting)	VIN(max)		1	0.1	10 10 	 mV(rms
VOLTAGE COMPARATOR	- -		,			
Voltage gain $1/$	Avo	R _L = 5.1 kΩ	1	55	100	dB
Output leakage current	ILOUT	V ₀ = 12 V	1	.001	0.1	μА
Output voltage low	Y _{OUT(min)}	I _C = 12 mA	1	50	500	mΥ
	<u> </u>		2,3		1,000	<u> </u>
INTERNAL REFERENCE						
Voltage level	V _{REF}	Measured at pin 10	1	4.9	5.7	Į v
	i		1 2, 3	4.75	 5.85	

1/ Guaranteed, if not tested.

- 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition A or C using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method $\overline{5005}$ of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

MILITARY DRAWING	SIZE A		DWG NO. 77050				
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO			REV A		PAGE 5		



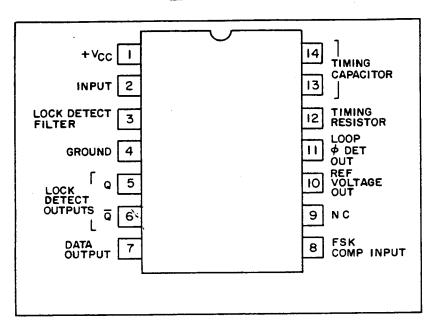


FIGURE 1. Terminal connections (top view).

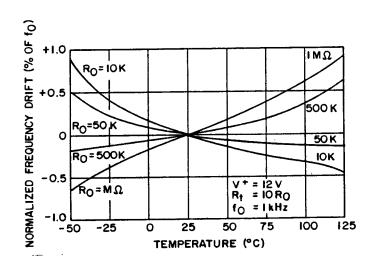
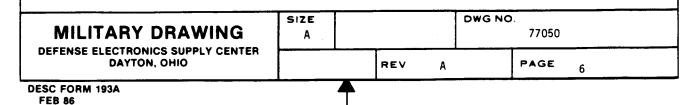


FIGURE 2. Typical center frequency drift vs temperature.



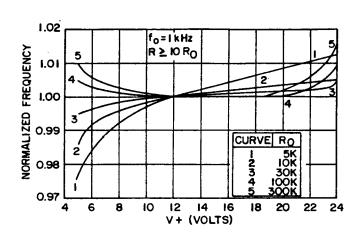


FIGURE 3. Typical f_0 vs power supply characteristics.

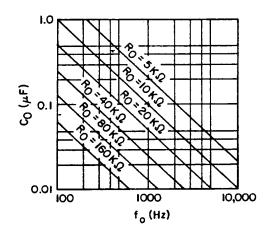


FIGURE 4. VCO frequency vs timing resistor.

	SIZE	DWG	NO.	
MILITARY DRAWING	Α	· .	77050	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO		REV A	PAGE 7	
DESC FORM 193A FEB 86				



- a. Tests shall be as specified in table II herein.
- b. Subgroups 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A or C using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

TABLE II. <u>Electrical test requirements</u>.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
 Interim electrical parameters (method 5004)	
 Final electrical test parameters (method 5004)	l 1*, 2, 3, 4, 5, 6
 Group A test requirements (method 5005)	l l 1, 2, 3, 4, l 5, 6, 7
 Groups C and D end-point electrical parameters (method 5005)	

^{*}PDA applies to subgroup 1.

5. PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

MILITARY DRAWING	SIZE A			DWG NO	DWG NO. 77050		
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO			REV		PAGE 8		

- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 Approved source(s) of supply. An approved source of supply is listed (Approved sources of supply are listed) herein. Additional sources will be added as they become available. The vendor(s) listed herein has (have) agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number 1/	Replacement military specification part number			
7705001CX	07933	XR2211M/883B				

 $\frac{1}{}$ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

07933

Vendor name and address

Raytheon Company Semiconductor Division 350 Ellis Street Mountain View, CA 94040

MILITARY DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO

SIZE A DWG NO 77050